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Peak effect and its evolution with defect structure in $YBa_2Cu_3O_{7-\delta}$ thin films at microwave frequencies.

Tamalika Banerjee[1] *, D. Kanjilal[2] and R.Pinto[1] †
[1]*Department of Condensed Matter Physics and Materials Science,*
Tata Institute of Fundamental Research, Homi Bhabha Road, Mumbai 400 005, India
[2]*Nuclear Science Centre, Aruna Asaf Ali Marg, New Delhi 110 067, India*

Abstract

The vortex dynamics in $YBa_2Cu_3O_{7-\delta}$ thin films have been studied at microwave frequencies. A pronounced peak in the surface resistance, R_s, is observed in these films at frequencies of 4.88 and 9.55 GHz for magnetic fields varying from 0.2 T to 0.8 T. The peak is associated with an order-disorder transformation of the flux line lattice as the temperature or field is increased. The occurrence of the peak in R_s is crucially dependent on the depinning frequency, ω_p and on the nature and concentration of growth defects present in these films. Introduction of artificial defects by swift heavy ion irradiation with 200 MeV Ag ion at a fluence of 4×10^{10} ions /cm^2 enhances ω_p and suppresses the peak at 4.88 GHz but the peak at 9.55 GHz remains unaffected. A second peak at lower temperature has also been observed at 9.55 GHz. This is related to twin boundaries from angular dependence studies of R_s. Based on the temperature variation of R_s, vortex phase diagrams have been constructed at 9.55 GHz.

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* e-mail:tamalika@tifr.res.in

† e-mail:rpinto@tifr.res.in

The dynamics of vortices forming the flux line lattice (FLL) in the mixed state of type II superconductors has been a subject of great interest over the last fe w years [1-3]. The competition between intervortex interactions and pinning by disorder or defects [4-6] gives rise to the widely studied peak effect (PE) phenomenon which is the occurrence of a peak in the critical current density, J_c, below its superconducting-normal phase boundary. The earliest understanding of this phenomenon, involves the rapid softening of the elastic moduli of the FLL as H_{c_2}(T) is approached which allows pinning sites to distort the lattice more strongly, leading to a sharp rise in the critical current density [7-9]. This is described in the Larkin-Ovchinnikov collective pinning model as a reduction in the correlation volume V_c which is the characteristic size over which the FLL is ordered and where the effective pinning force on the FLL is given by

$$BJ_c(H) = (n_p\langle f^2\rangle/V_c)^{1/2} \tag{1}$$

where n_p is the density of pinning sites, f is the elementary pinning force parameter, B is the magnetic induction and V_c is the volume of Larkin domain. This scenario is generally true for weak collective pinning (point defects and uncorre lated defects) where $n_p >> n_v$ (n_v is the vortex density). On the other hand, there is increasing evidence that for strong dilute pinning (eg., twin planes in twinned crystals) where $n_p < n_v$, the transition to disorder above the peak temperature T_p, is more likely to be accompanied by a plastic motion of the vortex lattice.

Till date, the statics and dynamics of the FLL have been probed at low frequencies by measurements of the dc critical current density J_c and very few studies have been done in the radiowave or microwave regime. At high frequencies (low currents) the vortices undergo reversible oscillations and are less sensitive to flux creep [10]. In this sense, the small probe current leads to enhanced dissipation, which would otherwise have occurred for either high dc transport current or a large external magnetic field. The directly accessible quantity characterizing this response is the surface impedance given as $Z_s = R_s + iX_s$ where the surface resistance R_s determines dissipation and yields information about the vortex dynamics and X_s, the surface reactance, is a measure of the London penetration depth.

The earliest theoretical model of the dynamics of the Lorentz force of alternating screening currents at these frequencies was given by Gittleman and Rosenblum [11] and thereafter refined considerably [12]. For vortices oscillating close to the minimum of the pinning potential and experiencing a restoring force , κ_p, (determined by the curvature of the pinning potential), the equation of motion for a massless flux line, neglecting Hall and stochastic thermal force, is given as

$$\eta\dot{x} + \kappa_p x = J \times \phi_0 \tag{2}$$

where $J(t)$ is the microwave driving current, x is the displacement from equilibrium and $\eta = \phi_0 H_{c_2}/\rho_n$ is the Bardeen-Stephen viscous drag coefficient. The vortex impedance is thus given by

$$\rho_v = \frac{\phi_0 B}{\eta}\frac{1}{(1 + i\omega_p/\omega)} = \frac{\omega^2 - i\omega\omega_p}{\omega^2 + \omega_p^2}\frac{H}{H_{c_2}}\rho_n \tag{3}$$

where ω_p is the depinning frequency. The characteristic depinning frequency, $\omega_p = \kappa_p/\eta$, separates the low frequency regime ($\omega < \omega_p$) dominated by pinning with inductive response, from a high frequency regime ($\omega > \omega_p$) of free vortex flow with dissipation. In this limit [13] R_s is given as

$$R_s = \left(\frac{2H}{H_{c_2}}\right)^{1/2} \left(\frac{\omega\omega_p}{\omega^2 + \omega_p^2}\right)^{1/2} \tag{4}$$

From the above expression we see that for $\omega < \omega_p$, R_s increases with ω whereas for $\omega >> \omega_p$ the response reduces to that of a normal metal with $R_s = \rho_n H/H_{c_2}$.

Although there have been few studies of the vortex dynamics at microwave and radio frequencies there are no reports on the observation of PE at microwave or radio frequency in either low T_c or high T_c superconductors. However, recently we have reported [14] the first observation of PE in $DyBa_2Cu_3O_{7-\delta}$ (DBCO) thin films at a frequency of 9.55 GHz. The observation of the peak was explained within the Larkin Ovchinnikov scenario in the weak collective pinning regime. Furthermore, it was shown that κ_p (or ω_p), has a similar temperature and field variation as J_c and shows a peak near T_c (H_{c_2}) which in turn reflects as a minimum in R_s. We had also conjectured that the shift in the position of the peak in R_s with frequency arises due to the pinning of vortices (or bundles of vortices) in potentials of varying strength κ_p causing a distribution in time scales of the FLL.

Pinning of the FLL due to material disorder (growth defects as dislocations, stacking faults, point and surface defects) plays an important role in the transport properties of type II superconductors. Ion irradiation is a well-established method to increase the lattice defect concentration in a controlled way with homogenous spatial distribution over the sample area [15]. Whereas point defects are not so effective pinning centres because of their extremely small coherence length, cylindrical defects of radius equal to the coherence length act as strong pinning centres. The strong pinning provided by such columnar defects (CDs) completely alters the eq uilibrium properties of a clean vortex state [16]. In this work, we show that the peak in R_s of $YBa_2Cu_3O_{7-\delta}$ (YBCO) thin films at 4.88 GHz caused by random uncorrelated defects is suppressed with the introduction of artificial correlated columnar defects by 200 MeV Ag ion irradiation while the peak at 9.55 GHz remains unaffected.

For the present study, several c-axis oriented YBCO ($T_c = 92 \pm 0.2$ K) thin films (thickness 2500 Å), were grown by pulsed laser deposition technique on single crystal ⟨100⟩ $LaAlO_3$ substrates. For microwave transmission studies, the films were patterned into linear microstrip resonators of width 175 μm and length 9 mm using UV photolithographic techniques. Details of the microwave measurements and determination of R_s have been described earlier [17]. DC magnetic field varying from 0.2 T up to 0.9 T was applied perpendicular to the film plane (parallel to the c-axis of the film) using a conventional electromagnet. Since the penetrati on depth, λ, of YBCO thin films is in the range 1500-2500 Å for the temperature range 0-77 K [17], a major fraction of the YBCO microstrip resonator is driven into the mixed state at the microwave frequencies. The temperature instability during measurements was always < 30 mK. Irradiation was carried out using the 15 U D Pelletron accelerator at Nuclear Science Centre, New Delhi using 200 MeV $^{109}Ag^{+14}$ ions at a fluence of 4×10^{10} ions/cm^2 (corresponding to a matching field $B_\phi \sim 0.8$ T). For this choice of ion species and energy (electronic energy loss =2.3 keV/Å) columnar defects (CDs) are created [18].

The variation of R_s with temperature, before and after irradiation, at various magnetic fields at 4.88 GHz (corresponding to the fundamental excitation of the microstrip) is shown in Fig.1. At field values > 0 T, R_s is found to exhibit a peak followed by a sudden dip just before T_c. Irradiation with 200 M eV Ag ions at a fluence of 4×10^{10} ions/cm^2 causes the peaks to be suppressed. Fig.2 shows the temperature variation of R_s at 9.55 GHz (first harmonic excitation of the microstrip). Here we observe a second peak at lower temperatures for fields > 0 T. However, there is no suppression of peaks with 200 MeV Ag irradiation. A manifestation of irradiation induced disorder is reflected in an increase in R_s at field values upto the matching field of 0.8 T. At the matching field of 0.8 T, the effect of pinning by CDs far surpasses the effect of disorder introduced by irradiation and a drop in the R_s values is observed.

In the weak collective pinning scenario, the motion of the vortices inside V_c is small as compared to the overall pinning potential arising collectively from such pinning sites inside the Larkin domain. At this frequency, the restoring force κ_p acting on the vortices causes it to oscillate in the potential well which causes depinning of the vortices near T_c (at T_{p1}). This order-disorder transformation at T_{p1} exhibits as a single peak in R_s. However, at a higher frequency of 9.55 GHz, an additional peak at lower temperature (T_{p2}) is observed along with the peak at T_{p1}. It is believed that the origin of these multiple peaks could be various defect structures commonly found in thin films. Thin films grown by laser ablation have various types of defects as uncorrelated defects like point defects, oxygen deficiencies or their clusters, secondary phase precipitates or correlated defects like twin boundaries. The differences in the pinning interaction of these defect sites with the vortices causes the system to have a distribution in time scales and leads to various peak structures at different temperatures [4] when the measurement frequency is changed from 4.88 to 9.55 GHz. The observation of secondary peaks in low frequency J_c-T plots and their possible origin has been widely studied in literature [19]. It is likely that the secondary peak (at T_{p2}) observed at 9.55 GHz in our case could be due to twin boundaries - a common defect structure in these thin films. An angular correlation of this peak at T_{p2} with the magnetic field was done at 9.55 GHz and is shown in the top inset of Fig.2. It is observed that the peak at T_{p2}, is significantly suppressed when the external magnetic field is perpendicular to the c-axis of the film. However, the peak at T_{p1} does not have any angular dependence with the external magnetic field. This indicates that the peak at T_{p2} arises due to pinning by twin boundaries. Recent magneto-optical imaging and magnetization measurements have also pointed out that twin boundaries are easy paths for flux pinning [20,21].

The bottom inset in Fig.2 is a plot of $1/R_s$ (normalized) vs. T at a field value of 0.4 T. To understand the significance of this plot let us go back to the correlation of J_c with ω_p and hence R_s [14]. It is seen that the variation of $1/R_s$ (normalized) is similar to that of J_c and shows a peak before T_c (H_{c_2}). Ion irradiation and creation of correlated defect centres as CDs are well known to strongly pin the flux lines in such defect sites. Liberating a vortex from CDs requires considerable amount of energy causing an increase in J_c. This is reflected in an increase in $1/R_s$ (normalized) in our case.

Within the collective pinning scenario for weak pinning centres, the model variation of depinning frequency ω_p with T/T_c, which shows a minimum followed by a peak at T_p, critically depends on the measurement frequency (as proposed in our earlier paper [14]), curve as shown by 'a' in Fig.3. Thus, at a frequency 4.88 GHz (where $\omega < \omega_p^{dip}$ or ω_1 in curve 'a' of Fig.3), the peak observed is less pronounced as compared to that at 9.55 GHz (where $\omega_p^{peak} > \omega_2 > \omega_p^{dip}$, curve 'a' in Fig.3). Artificially introduced defects like columnar defects lying in the vicinity of the other scattered defects enhance their pinning strength and prevent a flux line to be depinned at 4.88 GHz from such sites. In other words, ω_p of the YBCO film is increased above 4.88 GHz which is depicted in the upward shift of the model plot (curve 'b' of Fig.3). However, the irradiation induced enhancement in ω_p is insufficient to keep the vortices pinned at 9.55 GHz; hence there is no suppression of T_{p1} after irradiation.

Based on the temperature variation of R$_s$ (at 9.55 GHz), tentative vortex phase diagrams have been constructed and shown in Figs. 4a &b for the pristine and irradiated sample, respectively. The onset of order-disorder transformation of the FLL indicated by T$_{onset}$ (onset of peak in R$_s$) corresponds to a minimum in $\omega_p(\omega_p^{dip})$. The process of disordering is complete at the peak in $\omega_p(\omega_p^{peak})$ which corresponds to the minimum of R$_s$ at T$_{p_1}$. Hence, the phase diagram shown comprises an ordered vortex state, which crosses over to a fully disordered state via a partially ordered vortex state as the temperature or field is increased. The crossover region, or the partially ordered vortex solid region, broadens out over a greater temperature range in the case of the irradiated sample. The subsequent transformation to a totally disordered or normal phase is indicated by T$_c$ (deduced from microwave data, R$_s$ $\sim 10m\Omega$). This indicates that irradiation introduces disorder in the system which modifies the dynamics of the vortex lattice in a major way.

In summary, we have studied peak effect at microwave frequencies (4.88 and 9.55 GHz) in YBCO thin films for H // c before and after irradiation with 200 MeV Ag ions at a fluence of 4×10^{10} ions/cm^2 . We have shown that the peak in R$_s$ at such frequencies critically depends on the nature and concentration of defects. A suppression of the peak at 4.88 GHz is observed after irradiation due to enhanced pinning by the columnar defects which shifts the ω_p vs. T/T$_c$ model plot (proposed in our earlier work) to higher ω_p values. Angular-dependence measurements of R$_s$ with magnetic field indicate that the second peak at T$_{p2}$ observed at 9.55 GHz, is related to the twin boundaries. From the phase diagrams, based on the temperature variation of R$_s$ at 9.55 GHz, we see that irradiation induced disorder broadens the crossover region between the ordered and the disordered phase. We have carried out our analysis using the Gittlemann-Rosenblaum model where the effects of thermally activated flux motion are neglected. It would be interesting to study the PE phenomenon and the vortex dynamics by using a more refined model where the role of thermal effects, at these frequencies, are incorporated.

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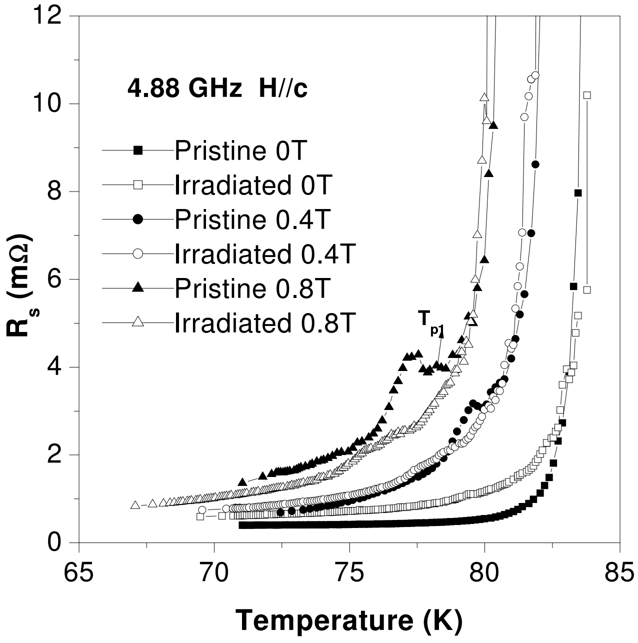

Fig.1 : R_s vs. T plots at 4.88 GHz for various applied fields (// c) for both pristine and irradiated films.

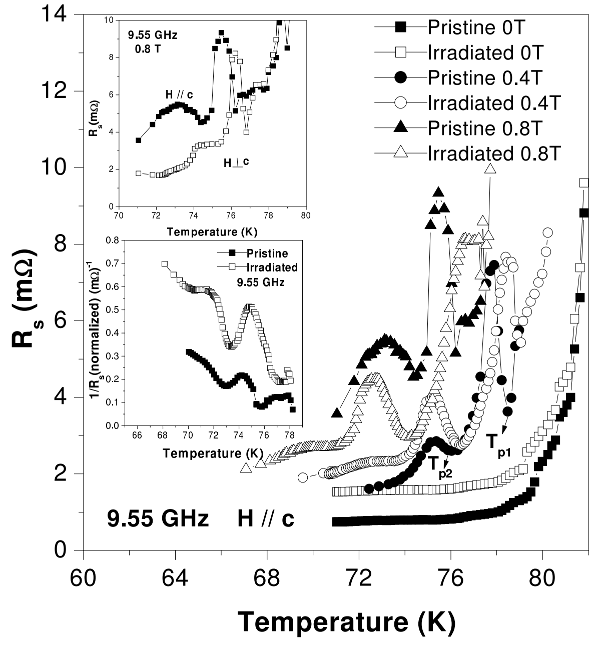

Fig.2: R_s vs. T plots at 9.55 GHz for various applied fields (// c) for both pristine and irradiated films. Top Inset shows R_s vs. T plot at 0.8T for H // c and H ⊥ c at 9.55 GHz. Bottom Inset shows $1/R_s$ (normalized) vs. T plots at 0.4 T for H // c at 9.55 GHz.

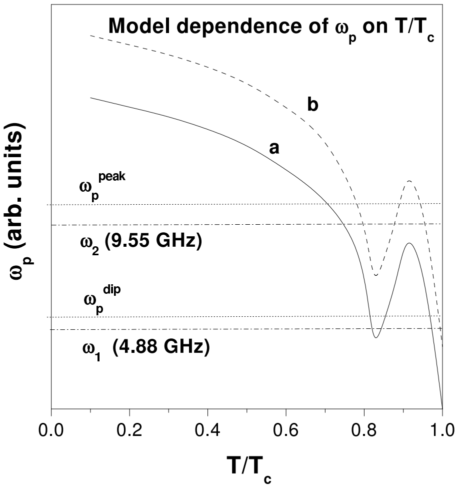

Fig.3 Model dependence of ω_p on T/T$_c$ for (a) pristine sample and (b) the sample irradiated with 200 MeV Ag ions at a fluence of 4×10^{10} ions/cm^2.

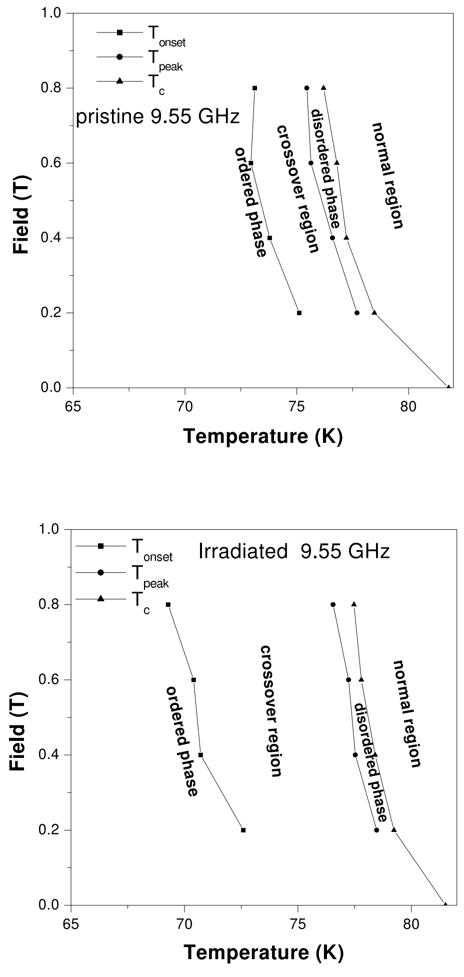

Fig.4 . Phase diagrams: (a) At 9.55 GHz, Pristine sample (b) At 9.55 GHz, Irradiated sample.